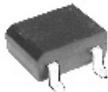




LI DE HENG ELECTRONICS

B05S thru B10S

0.5 A Single-Phase Glass Passivated Bridge Rectifiers  
Rectifier Reverse Voltage 50 to 1000V

MINI-DIP

## Features

- This series is UL listed under the Recognized Component Index, file number E142814
- Ideal for surface mount application
- The plastic material used carries Underwriters Laboratory flammability recognition 94V-0
- Surge overload ratings to 30 amperes
- High temperature soldering guaranteed 265°C/10 seconds at 5 lbs (2.3kg) tension

## Mechanical Data

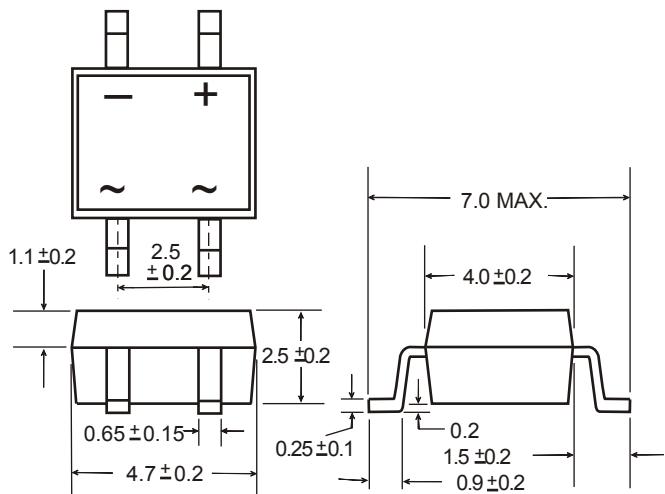
Case: Molded plastic

Terminals: Plated leads solderable per MIL-STD-202,  
Method 208

Polarity: Marked on body

Mounting Position: Any

Weight: 0.0044 ounce, 0.125 grams (approx)



Dimensions in millimeters(1mm = 0.0394")

## Maximum Ratings & Thermal Characteristics

Rating at 25°C ambient temperature unless otherwise specified, Resistive or Inductive load, 60 Hz.  
For Capacitive load derate current by 20%.

Parameter	Symbol	B05S	B1S	B2S	B4S	B6S	B8S	B10S	unit
Maximum repetitive peak reverse voltage	VRRM	50	100	200	400	600	800	1000	V
Maximum RMS bridge input voltage	VRMS	35	70	140	280	420	560	700	V
Maximum DC blocking voltage	VDC	50	100	200	400	600	800	1000	V
Maximum average forward rectified output current at TA=40°C (*3)	IF(AV)				0.5				A
					0.8*				
Peak forward surge current single sine-wave superimposed on rated load (JEDEC Method)	IFSM				30				A
Rating for fusing ( t<8.3ms)	I <sup>2</sup> t				10				A <sup>2</sup> sec
Typical thermal resistance per element(1)	ReJA				110				°C /W
Typical junction capacitance per element (2)	C <sub>j</sub>				25.0				pF
Operating junction and storage temperature range	T <sub>j</sub> , T <sub>TSG</sub>				-55 to + 150				°C

## Electrical Characteristics

Rating at 25°C ambient temperature unless otherwise specified. Resistive or Inductive load, 60Hz.  
For Capacitive load derate by 20 %.

Parameter	Symbol	B05S	B1S	B2S	B4S	B6S	B8S	B10S	Unit
Maximum instantaneous forward voltage drop per leg at 0.5A	VF				1.1				V
Maximum DC reverse current at rated TA =25 °C DC blocking voltage per element TA =125 °C	IR				10				μA

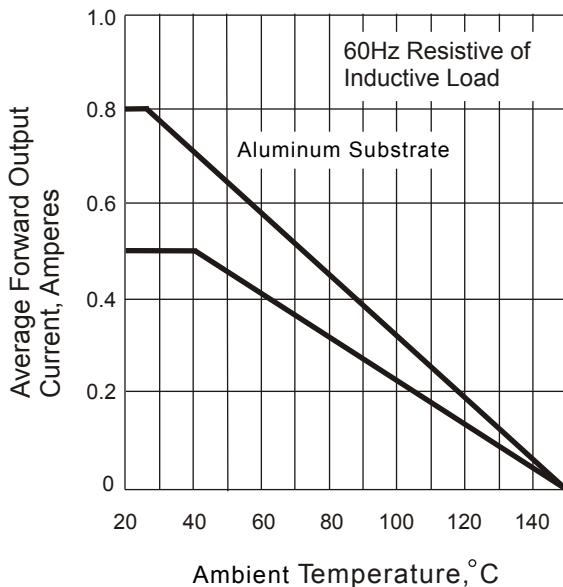
Notes: (1)Thermal resistance from Junction to Ambent on P.C.board mounting.

(2)Measured at 2.0MHz and applied reverse voltage of 4.0 volts.

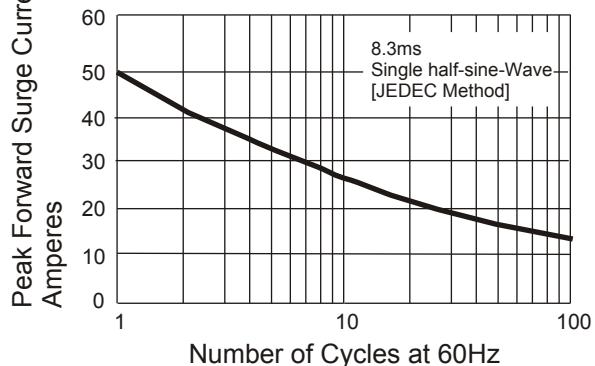
(3)R-load on aluminum substrate TA=25°C.

**Rating and Characteristic Curves ( TA=25°C Unless otherwise noted )**  
**B05S thru B10S**

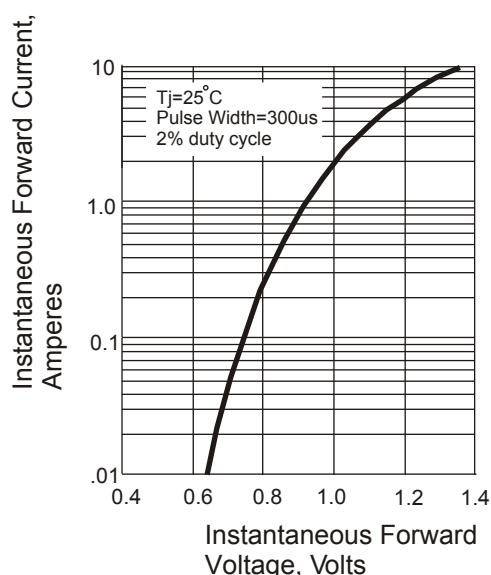
**Fig. 1 Derating Curve for Output Rectified Current**



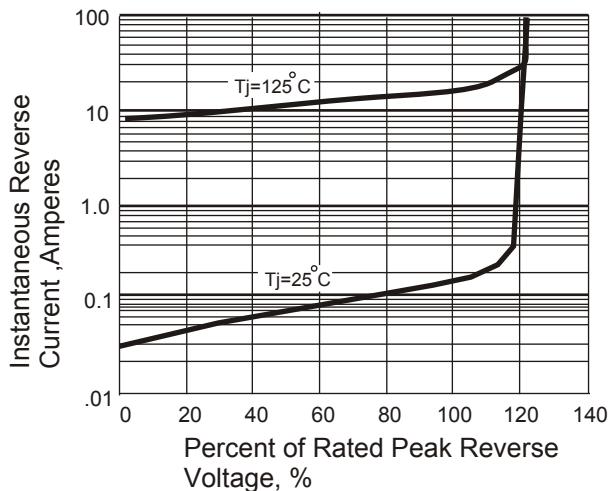
**Fig. 2 Maximum Non-repetitive Peak Forward Surge Current**



**Fig. 3 Typical Instantaneous Forward Characteristics**



**Fig. 4 Typical Reverse Characteristics**



**Fig. 5 Typical Junction Capacitance**

